

2822



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Oleg Siniaguine  
 Assignee: Tru-Si Technologies, Inc.  
 Title: Semiconductor Structures Having Multiple Conductive Layers In An Opening, And Methods For Fabricating Same  
 Application No.: 09/941,447 Filing Date: August 28, 2001  
 Examiner: Thomas, Toniae M. Group Art Unit: 2822  
 Docket No.: M-9999-1D US

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 San Jose, California  
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Commissioner For Patents  
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**INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. § 1.97(B) WITH  
 CERTIFICATION UNDER 37 C.F.R. § 1.97(E)(1)**

Dear Sir:

Pursuant to 37 C.F.R. § § 1.56, 1.97 and 1.98, Applicants wish to call the documents listed on the enclosed Form PTO-1449 (1 page) to the Examiner's attention for the above-identified patent application. Copies of the listed documents are enclosed. The documents were first cited by the European Patent Office in a corresponding PCT Application No. PCT/US 02/05371. The relevance of any foreign language documents is explained in the accompanying English abstracts and the enclosed PCT International Search Report.

Citation of the above documents shall not be construed as:

1. an admission that the documents are necessarily prior art with respect to the instant invention;
2. a representation that a search has been made, other than as described above; or

3. an admission that the information cited herein is, or is considered to be, material to patentability as defined in § 1.56(b).

The undersigned hereby certifies in accordance with § 1.97(e)(1) that each item of information contained in this Information Disclosure Statement was first cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this Information Disclosure Statement.

**Statement under 37 C.F.R. §1.704(d)**

Each item of information contained in the information disclosure statement was cited in a communication from a foreign patent office in a counterpart application and this communication was not received by any individual designated in §1.56(c) more than thirty days prior to the filing of the information disclosure statement.

No fee is believed to be required for this Information Disclosure Statement. If a fee is required, please charge the fee to deposit account 50-2257. This paper is submitted in duplicate.

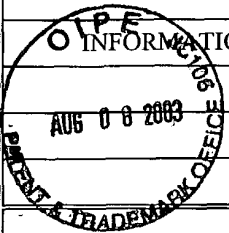
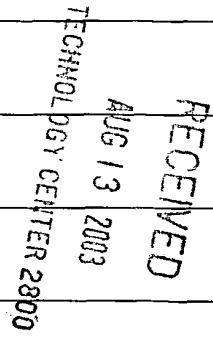
I hereby certify that this correspondence is being deposited with the United States Postal Service as First Class Mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on August 1, 2003.

Michael Shenker August 1, 2003  
Attorney for Applicant(s) Date of Signature

Respectfully submitted,

*Michael Shenker*

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Reg. No. 34,250

U.S. Department of Commerce, Patent and Trademark Office					Atty Docket No.		Serial No.	
					M-9999-1D US		09/941,447	
 INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use several sheets if necessary)					Applicant(s)			
					Oleg Siniaguine			
					Filing Date		Group	
					August 28, 2001		2822	
U.S. Patent Documents								
*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate	
	AA	6,122,187	19 Sept. 2000	Ahn et al.				
	AB	6,184,060	6 Feb. 2001	Siniaguine				
	AC							
	AD							
	AE							
	AF							
	AG							
	AH							
	AI							
	AJ							
	AK							
Foreign Patent Documents								
							Translation	
		Document	Date	Country	Class	Subclass	Yes	No
	AL							
	AM							
	AN							
	AO							
	AP							
OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)								
	AQ							
	AR							
	AS							
Examiner			Date Considered					
*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.								